

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# LA6242H — For CD Player 4-channel Bridge (BTL) Driver

#### Overview

The LA6242H is a 4-channel motor driver IC for home and car CD players. It provides a pin for switching the channel 1 input.

#### **Functions**

- Four bridge-connected (BTL) power amplifier circuits
- IO max: 1A
- Built-in level shifter circuits
- Muting circuit (on/off control for all outputs)
- High output voltage (dynamic range): 6.5V (typical, channel 1 only)
- Built-in input operational amplifier (channel 1 only)
- Channel 1 input operational amplifier switching function
- Built-in regulator that uses an external PNP transistor and is set by the value of an external resistor.
- Built-in overheat protection (Thermal shutdown) circuit (Design guarantee)

#### **Specifications**

#### **Maximum Ratings** at Ta = 25°C

•				
Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V <sub>CC</sub> S	*1	14	V
	V <sub>CC</sub> P*	V <sub>CC</sub> P1, V <sub>CC</sub> P2 *1	14	V
Maximum input voltage	V <sub>IN</sub> B		13	V
Maximum output current	I <sub>O</sub> max	Each output	1	Α
MUTE pin voltage	V <sub>MUTE</sub>		13	V
Allowable power dissipation	Pd max	Independent IC	0.8	W
		Mounted on the specified board *2	1.8	W
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

<sup>\*1:</sup> All of the power supply pins, V<sub>CC</sub>S, V<sub>CC</sub>P1, and V<sub>CC</sub>P2, must be connected to the power supply system externally to the IC.

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<sup>\*2:</sup> Specified board: 114.3mm × 76.1mm × 1.6mm, glass epoxy board.

#### **LA6242H**

#### **Recommended Operating Conditions** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	VCC		5 to 13	V

# $\textbf{Electrical Characteristics} \ \text{at Ta} = 25^{\circ}\text{C}, V_{CC}\text{S} = V_{CC}\text{P1} = V_{CC}\text{P2} = 8 \ \text{V}, \ \text{VREF} = 2.5 \ \text{V}, \ \text{MUTE} = 5 \ \text{V}$

Danamatan	Command and	Condition -		Ratings		l lait
Parameter	Symbol	Conditions	min	typ	max	Unit
Overall						
Quiescent current 1	I <sub>CC</sub> -ON	All channel outputs on, MUTE pin: high		30	45	mA
Quiescent current 2	I <sub>CC</sub> -OFF	All channel outputs off, MUTE pin: low		5	10	mA
Muting function on voltage	V <sub>MUTE</sub> -ON	MUTE *1	2			V
Muting function off voltage	V <sub>MUTE</sub> -OFF	MUTE *1			0.5	V
Thermal shutdown	TSD	*4	150	175	200	°C
BTL Amplifier (Channel 1) (Output	Amplifier Block)					
Input amplifier offset voltage	V <sub>OFF</sub> OP-AMP	Channel 1, input operational amplifiers A and B	-50		+50	mV
Output voltage	V <sub>O</sub> 1	$R_L = 8\Omega *2$	6.2	6.5		V
I/O gain	VG1	*3	5.4	6	6.6	Times
Slew rate	SR1	With the amplifier operating independently, twice		0.5		V/μs
		the value measured between outputs *3,*4				
Input Operational Amplifier	T		ı	1		1
Output offset voltage	V <sub>OFF</sub> 1	Input operational amplifiers A and B	-10		+10	mV
OP-AMP_SINK	OP_SINK	Input operational amplifier sink current	2			mA
OP-AMP_SOURCE	OP_SOURCE	Input operational amplifier source current	300	500		μΑ
Input Operational Amplifier Switching						
Input amplifier switching voltage 1	V <sub>IN</sub> 1-SW	Channel 1, with input operational amplifier B selected *5			0.5	V
Input amplifier switching voltage 2	V <sub>IN</sub> 1-SW	Channel 1, with input operational amplifier A selected *5	2			V
BTL Amplifier (Channels 2 to 4) (C	Output Amplifier Blo	ck)				
Output offset voltage	V <sub>OFF</sub> 2	Between the + and - outputs for each channel	-50		+50	mV
Output voltage	V <sub>O</sub> 2	$R_L = 8\Omega$ , between the $+$ and $-$ outputs for each channel *2	5	5.4		V
I/O gain	VG2		5.4	6	6.6	Multip lier
Slew rate	SR2	Amplifier independently, twice the value measured between outputs *3,*4		0.5		V/μs
Regulator Voltage		. ,				
VREG output voltage	VREG	*6	1.21	1.26	1.31	V
REG-IN sink current	REG-IN-SINK	The base current of the external PNP transistor	5	10		mA
Line regulation	ΔV <sub>O</sub> LN	$6V \le V_{CC} \le 12V$ , $I_O = 200mA$		20	150	mV
Load regulation	ΔV <sub>O</sub> LD	$5mA \le I_O \le 200mA$		50	200	mV

<sup>\*1:</sup> When the MUTE pin is high, the outputs will be on, and when low, the outputs will be off. (In the amplifier output off state, the outputs are in the high-impedance state.) This operation applies to all channels.

<sup>\*2:</sup> The voltage across the load terminals when an  $8\Omega$  load is connected across the outputs. With the input either high or low. With the output in the saturated

<sup>\*3:</sup> The channel 1 input operational amplifier has a 0dB gain, i.e. it is a buffer amplifier.

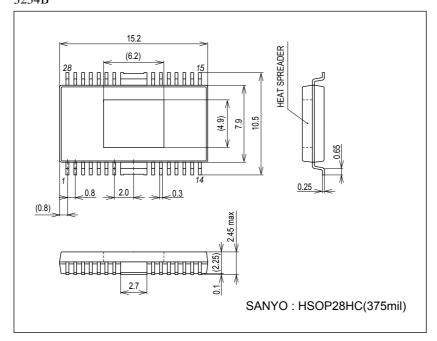
<sup>\*4:</sup> Design guarantee value

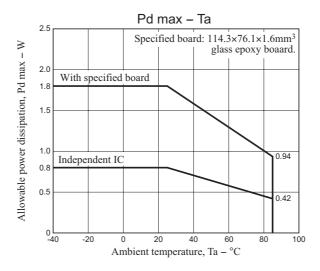
 $<sup>^{\</sup>star}$ 5: When V<sub>IN</sub>1-SW is high, operational amplifier A operates, and when low, operational amplifier B operates.

 $<sup>^{\</sup>star}6$ : For testing, short the REGOUT to the collector of the external PNP-transistor.

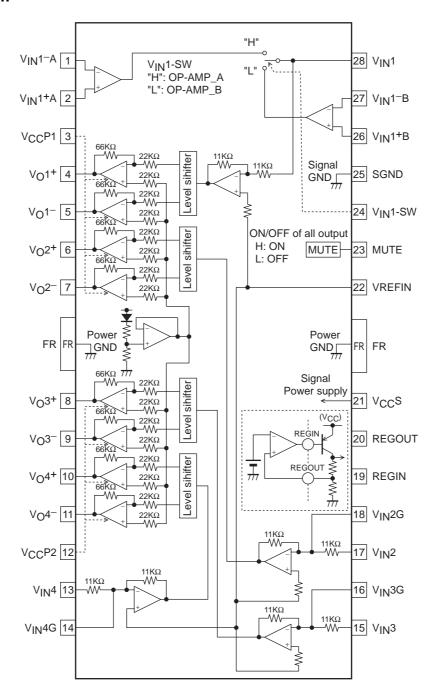
# **Package Dimensions**

unit: mm (typ) 3234B





## **Block Diagram**



## LA6242H

## **Pin Functions**

2 3 4 5 5 6 7 8 9 9	V <sub>IN</sub> 1 <sup>-</sup> A V <sub>IN</sub> 1 <sup>+</sup> A V <sub>CC</sub> P1 V <sub>O</sub> 1 <sup>+</sup> V <sub>O</sub> 1 <sup>-</sup> V <sub>O</sub> 2 <sup>-</sup> V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup> V <sub>O</sub> 4 <sup>-</sup>	Channel 1 input amplifier A inverting input  Channel 1 input amplifier A non-inverting input  Channels 1 and 2: power stage power supply  Channel 1 output (+)  Channel 1 output (-)  Channel 2 output (+)  Channel 2 output (-)  Channel 3 output (-)  Channel 3 output (-)  Channel 4 output (+)
3	V <sub>CC</sub> P1 V <sub>O</sub> 1 <sup>+</sup> V <sub>O</sub> 1 <sup>-</sup> V <sub>O</sub> 2 <sup>+</sup> V <sub>O</sub> 2 <sup>-</sup> V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channels 1 and 2: power stage power supply  Channel 1 output (+)  Channel 1 output (-)  Channel 2 output (+)  Channel 2 output (-)  Channel 3 output (-)  Channel 3 output (-)
4	V <sub>O</sub> 1 <sup>+</sup> V <sub>O</sub> 1 <sup>-</sup> V <sub>O</sub> 2 <sup>+</sup> V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channel 1 output (+) Channel 2 output (+) Channel 2 output (-) Channel 3 output (+) Channel 3 output (-)
5 ° ° ° ° ° ° ° ° ° ° ° ° ° ° ° ° ° ° °	V <sub>0</sub> 1 <sup>-</sup> V <sub>0</sub> 2 <sup>+</sup> V <sub>0</sub> 2 <sup>-</sup> V <sub>0</sub> 3 <sup>+</sup> V <sub>0</sub> 3 <sup>-</sup> V <sub>0</sub> 4 <sup>+</sup>	Channel 1 output (-) Channel 2 output (+) Channel 2 output (-) Channel 3 output (+) Channel 3 output (-)
6 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	V <sub>O</sub> 2 <sup>+</sup> V <sub>O</sub> 2 <sup>-</sup> V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channel 2 output (+) Channel 2 output (-) Channel 3 output (+) Channel 3 output (-)
7 8 9	V <sub>O</sub> 2 <sup>-</sup> V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channel 2 output (-) Channel 3 output (+) Channel 3 output (-)
8 '	V <sub>O</sub> 3 <sup>+</sup> V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channel 3 output (+) Channel 3 output (-)
9 \	V <sub>O</sub> 3 <sup>-</sup> V <sub>O</sub> 4 <sup>+</sup>	Channel 3 output (–)
	V <sub>O</sub> 4 <sup>+</sup>	
40		Channel 4 output (+)
10	$V_O4^-$	
11 \		Channel 4 output (–)
12	V <sub>CC</sub> P2	Channels 3 and 4: power stage power supply
13	V <sub>IN</sub> 4	Channel 4 input
14	V <sub>IN</sub> 4G	Channel 4 input (gain adjustment)
15 \	V <sub>IN</sub> 3	Channel 3 input
16 \	V <sub>IN</sub> 3G	Channel 3 input (gain adjustment)
17 ١	V <sub>IN</sub> 2	Channel 2 input
18 \	V <sub>IN</sub> 2G	Channel 2 input (gain adjustment)
19 I	REGIN	Base connection of external PNP transistor
20 I	REGOUT	Regulator error amplifier input (+)
21 \	V <sub>CC</sub> S	Signal system power supply
22	VREFIN	Reference voltage input
23 1	MUTE	Output on/off control
24	V <sub>IN</sub> 1-SW	Channel 1 input operational amplifier switching
25	SGND	Signal system ground
26	V <sub>IN</sub> 1 <sup>+</sup> B	Channel 1 amplifier B non-inverting input
27	V <sub>IN</sub> 1 <sup>-</sup> B	Channel 1 amplifier B inverting input
28	V <sub>IN</sub> 1	Channel 1 input and input operational amplifier output

Note: • The center frame (FR) is used as the power system ground (P-GND). Along with the signal system ground (SGND), this level must be the lowest potential in the system.

 $\bullet \text{ The V}_{CC}S \text{ (signal system power supply), V}_{CC}P1, \text{ and V}_{CC}P2 \text{ (output stage power supplies) must be shorted together externally. } \\$ 

# LA6242H

# **Pin Description**

	Descript	.1011		<u>,                                    </u>
Pin No.	Pin name	Function	Description	Equivalent circuit
1 2 26 27 28	V <sub>IN</sub> 1 <sup>-</sup> A V <sub>IN</sub> 1 <sup>+</sup> A V <sub>IN</sub> 1 <sup>+</sup> B V <sub>IN</sub> 1 <sup>-</sup> B V <sub>IN</sub> 1	Input (channel 1)	Inputs The total gain is set by setting the gain of the input amplifier.	V <sub>IN</sub> 1-* V <sub>IN</sub> 1 V <sub>IN</sub> 1+* 300Ω V <sub>IN</sub> 1+* 300Ω SGND
5	V <sub>O</sub> 1+ V <sub>O</sub> 1-	Output (channel 1)	Channel 1 output	V <sub>CC</sub> S V <sub>CC</sub> P V <sub>O</sub> 1 SGND
6 7 8 9 10 11	V <sub>O</sub> 2+ V <sub>O</sub> 2- V <sub>O</sub> 3+ V <sub>O</sub> 3- V <sub>O</sub> 4+ V <sub>O</sub> 4-	Output (channels 2 to 4)	Channel 2 to 4 outputs	V <sub>CC</sub> S V <sub>CC</sub> P V <sub>O</sub> SGND
23	MUTE	MUTE	Controls the on/off states of the corresponding channel output.  MUTE = high: Output on  MUTE = low: Output off  *: When the MUTE pin is open, the outputs will be off. (The same as when the MUTE pin is low.)	SGND TOWN TOWN TOWN TOWN TOWN TOWN TOWN TOWN
24	V <sub>IN</sub> 1-SW	Channel 1 input amplifier switching	Channel 1 input operational amplifier switching function. Either amplifier A or amplifier B is selected according to the voltage applied to the VIN1-SW pin. High: Vin_A Low: Vin_B	V <sub>CC</sub> S V <sub>IN</sub> 1-SW 2kΩ 2kΩ W

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Pin No.	Pin name	Function	Description	Equivalent circuit
17	V <sub>IN</sub> 2	Input	Inputs	,
18	V <sub>IN</sub> 2G	(channels 2 to 4)		
15	V <sub>IN</sub> 3			V <sub>IN</sub> Ο 11kΩ W
16	V <sub>IN</sub> 3G			
13	$V_{IN}4$			V <sub>IN</sub> G O
14	V <sub>IN</sub> 4G			V <sub>CC</sub> S O
				<b>★ ★★</b> [ ' ' ]
				3000
				300Ω
				Vref
				SGND
22	VREFIN	VREF	Reference voltage	_
	VINELLIN	VICEI	Treference voltage	v <sub>cc</sub> s
				↑ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓
				VREFIN 300Ω W
				T 👃
				SGND
				<u> </u>
19	REGIN	REG	Regulator block	v <sub>CC</sub> s
20	REGOUT			\$ \$ <b>+ + +</b> •
				G REGIN
				3000
				REGOUT
				T +
				\$ sgnd
				<del>///</del>

# MUTE, V<sub>IN</sub>1-SW

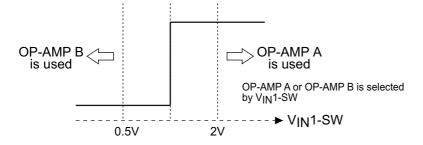
• Relationship between the MUTE pin and the outputs

MUTE	Outputs			
WOTE	CH1	CH2	CH3	CH4
Н	on			
L	off			

Note \*1: When the outputs are off, they are in the high-impedance state. \*2: The muting function applies to all channels.

• V<sub>IN</sub>1-SW and the channel 1 input operational amplifier

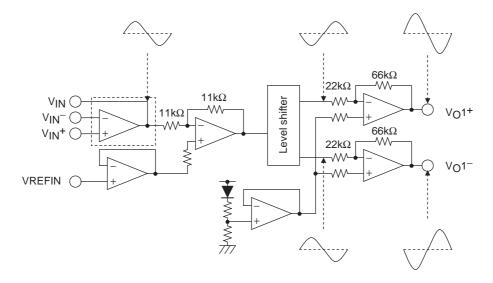
V <sub>IN</sub> 1-SW	Channel 1 input operational amplifier
Н	AMP_A
L	AMP_B



#### • Muting

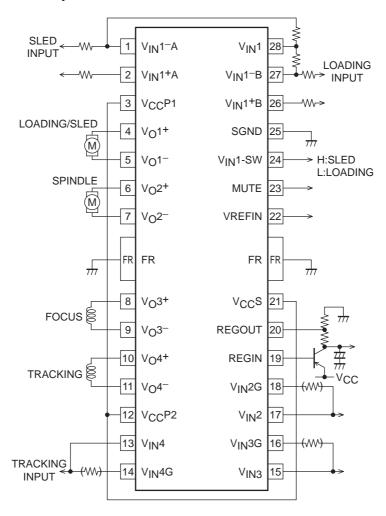
MUTE	Output amplifiers
L	off
Н	on

## Overview of the input/output relationship



Note: Only channel 1 has an added input operational amplifier.

#### **Application Circuit Example**



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